Supporting information

Enhanced Planar Perovskite Solar Cells Efficiency Exceeding 16%

via Reducing the Oxygen Vacancy Defect State in Titanium Oxide

Electrode

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Fig.S1 Some practical pictures for c-TiO₂ via sputtering with different oxygen flux value;



Fig.S2 XRD pattern for CH₃NH₃PbI_{3-x}Cl_x deposited on c-TiO₂/FTO substrate.



Fig.S3 Three dimensional AFM images of the sputtered $c-TiO_2$ films with increasing the oxygen flux value from 1 Sccm to 6 Sccm.

Table S1. The thickness value for $c-TiO_2$ prepared by 6 Sccm oxygen flux as the						
function of sputtering time						
Samples	c-TiO ₂ (1 min)	c-TiO ₂ (2 min)	c-TiO ₂ (3 min)	c-TiO ₂ (4 min)		
Thickness (nm)	15	47	89	128		



Fig.S4 J-V curves performance in light for p-PSCs based on sputtered c-TiO₂ as the function of

Table S2. The photovoltaic parameters extracted from Fig.S4					
Samples	V _{oc} (V)	J _{sc} (mA/cm ²)	FF (%)	PCE (%)	
1 min	0.92	19.05	57.17	10.02	
2 min	1.05	20.30	72.25	15.40	
3 min	1.01	19.86	65.50	13.14	
4 min	0.99	17.37	63.32	10.89	



Fig.S5 The current-voltage curves measurement in dark for sputtered $c-TiO_2$ on glass substrate as the function of oxygen flux value during the process of sputtering.

sputtering time.



Fig.S6 The hall mobility measurement for the $FTO/c-TiO_2$ electrodes prepared by different oxygen flux.

Table S3. The w	ork function (WF) value for	c-TiO ₂ measured by kelvin	n probe measurement
Samples	c-TiO ₂ (2 Sccm)	c-TiO ₂ (4 Sccm)	c-TiO ₂ (6 Sccm)
WF (eV)	5.0	4.6	3.8
a	28.56°	b 23.13	0

Fig.S7 Contact angles measurement between H_2O and $c-TiO_2$. (a) $c-TiO_2$ prepared by 6 Sccm oxygen flux; (b) $c-TiO_2$ prepared by 6 Sccm oxygen flux and UVO treatment.